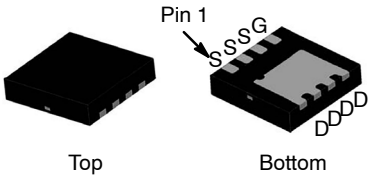
MOSFET – N-Channel, POWERTRENCH®

30 V, 14.8 A, 7.2 mΩ

FDMC7680

V_{DS}	$R_{DS(ON)}$ MAX	I_D MAX
30 V	7.2 mΩ @ 10 V	14.8 A
	9.5 mΩ @ 4.5 V	



WDFN8 3.3 × 3.3, 0.65P
CASE 511DH

General Description

This N-Channel MOSFET is produced using **onsemi**'s advanced POWERTRENCH process that has been especially tailored to minimize the on-state resistance. This device is well suited for Power Management and load switching applications common in Notebook Computers and Portable Battery Packs.

Features

- Max $R_{DS(on)}$ = 7.2 mΩ at V_{GS} = 10 V, I_D = 14.8 A
- Max $R_{DS(on)}$ = 9.5 mΩ at V_{GS} = 4.5 V, I_D = 12.4 A
- High Performance Technology for Extremely Low $R_{DS(on)}$
- Pb-Free, Halide Free and RoHS Compliant

Applications

- DC-DC Buck Converters
- Notebook Battery Power Management
- Load Switch in Notebook

FDMC7680 MARKING DIAGRAM

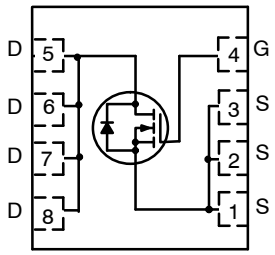


FDMC7680 = Device Code
A = Assembly Site
L = Wafer Lot Number
YW = Year Workweek
▪ = Pb-Free Package

MAXIMUM RATINGS (T_A = 25 °C unless otherwise noted)

Symbol	Parameter	Value	Unit
V_{DS}	Drain to Source Voltage	30	V
V_{GS}	Gate to Source Voltage	±20	V
I_D	Drain Current: Continuous, T_C = 25 °C Continuous, T_A = 25 °C (Note 1a) Pulsed	 18 14.8 45	A
E_{AS}	Single Pulse Avalanche Energy (Note 3)	72	mJ
P_D	Power Dissipation: T_C = 25 °C T_A = 25 °C (Note 1a)	 31 2.3	W
T_J, T_{STG}	Operating and Storage Junction Temperature Range	−55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



N-CHANNEL MOSFET

ORDERING INFORMATION

See detailed ordering and shipping information on page 6 of this data sheet.

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THERMAL CHARACTERISTICS

Symbol	Parameter	Value	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case	4.0	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient (Note 1a)	53	

ELECTRICAL CHARACTERISTICS (T_J = 25 °C unless otherwise noted)

Symbol	Parameter	Test Condition	Min	Typ	Max	Unit
OFF CHARACTERISTICS						
BV_{DSS}	Drain to Source Breakdown Voltage	I_D = 250 μA, V_{GS} = 0 V	30			V
ΔBV_{DSS} /ΔT_J	Breakdown Voltage Temperature Coefficient	I_D = 250 μA, referenced to 25 °C		15		mV/°C
I_{DSS}	Zero Gate Voltage Drain Current	V_{DS} = 24 V, V_{GS} = 0 V			1	μA
		V_{DS} = 24 V, V_{GS} = 0 V, T_J = 125 °C			250	
I_{GSS}	Gate to Source Leakage Current	V_{GS} = 20 V, V_{DS} = 0 V			100	nA
ON CHARACTERISTICS						
$V_{GS(th)}$	Gate to Source Threshold Voltage	V_{GS} = V_{DS}, I_D = 250 μA	1.2	2.0	3.0	V
$\Delta V_{GS(th)}$ /ΔT_J	Gate to Source Threshold Voltage Temperature Coefficient	I_D = 250 μA, referenced to 25 °C		−6		mV/°C
$R_{DS(on)}$	Static Drain to Source On Resistance	V_{GS} = 10 V, I_D = 14.8 A		5.8	7.2	mΩ
		V_{GS} = 4.5 V, I_D = 12.4 A		7.3	9.5	
		V_{GS} = 10 V, I_D = 14.8 A, T_J = 125 °C		7.4	9.2	
g_{FS}	Forward Transconductance	V_{DD} = 5 V, I_D = 14.8 A		68		S
DYNAMIC CHARACTERISTICS						
C_{iss}	Input Capacitance	V_{DS} = 15 V, V_{GS} = 0 V, f = 1 MHz		2145	2855	pF
C_{oss}	Output Capacitance			770	1020	pF
C_{rss}	Reverse Transfer Capacitance			75	115	pF
R_g	Gate Resistance	f = 1 MHz		0.5	1.6	Ω
SWITCHING CHARACTERISTICS						
$t_{d(on)}$	Turn-On Delay Time	V_{DD} = 15 V, I_D = 14.8 A, V_{GS} = 10 V, R_{GEN} = 6 Ω		12	22	ns
t_r	Rise Time			4	10	ns
$t_{d(off)}$	Turn-Off Delay Time			25	40	ns
t_f	Fall Time			3	10	ns
$Q_{g(TOT)}$	Total Gate Charge	V_{GS} = 0 V to 10 V, V_{DD} = 15 V, I_D = 14.8 A		30	42	nC
		V_{GS} = 0 V to 4.5 V, V_{DD} = 15 V, I_D = 14.8 A		14	19	nC
Q_{gs}	Gate to Source Charge	V_{DD} = 15 V, I_D = 14.8 A		7		nC
Q_{gd}	Gate to Drain “Miller” Charge	V_{DD} = 15 V, I_D = 14.8 A		4		nC

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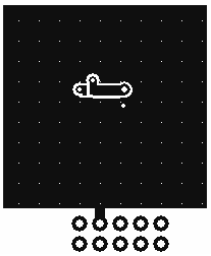
ELECTRICAL CHARACTERISTICS (T_J = 25 °C unless otherwise noted) (continued)

Symbol	Parameter	Test Condition	Min	Typ	Max	Unit
DRAIN-SOURCE DIODE CHARACTERISTICS						
V_{SD}	Source to Drain Diode Forward Voltage	V_{GS} = 0 V, I_S = 14.8 A (Note 2)		0.84	1.2	V
		V_{GS} = 0 V, I_S = 1.9 A (Note 2)		0.73	1.2	
t_{rr}	Reverse Recovery Time	I_F = 14.8 A, di/dt = 100 A/μs		34	54	ns
Q_{rr}	Reverse Recovery Charge			15	24	nC

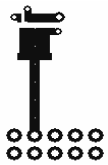
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

NOTES:

1. $R_{\theta JA}$ is determined with the device mounted on a 1 in^2 pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. $R_{\theta JC}$ is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design.



a) 53 °C/W when mounted on a 1 in^2 pad of 2 oz copper.



b) 125 °C/W when mounted on a minimum pad of 2 oz copper.

2. Pulse Test: Pulse Width < 300 μs, Duty cycle < 2.0%.
3. E_{AS} of 72 mJ is based on starting T_J = 25 °C, L = 1 mH, I_{AS} = 12 A, V_{DD} = 27 V, V_{GS} = 10 V.

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TYPICAL CHARACTERISTICS

(T_J = 25 °C unless otherwise noted)

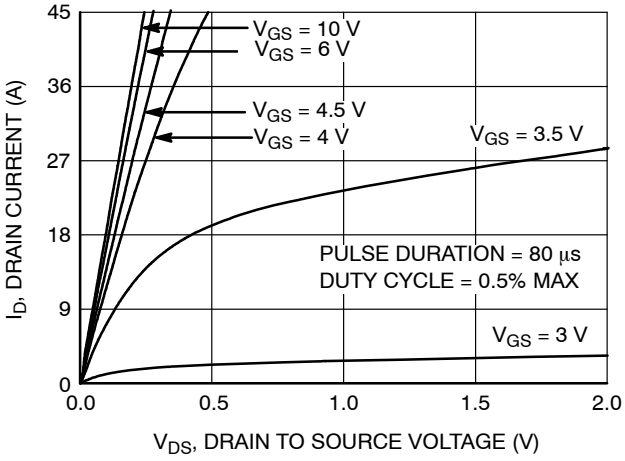

Figure 1. On-Region Characteristics

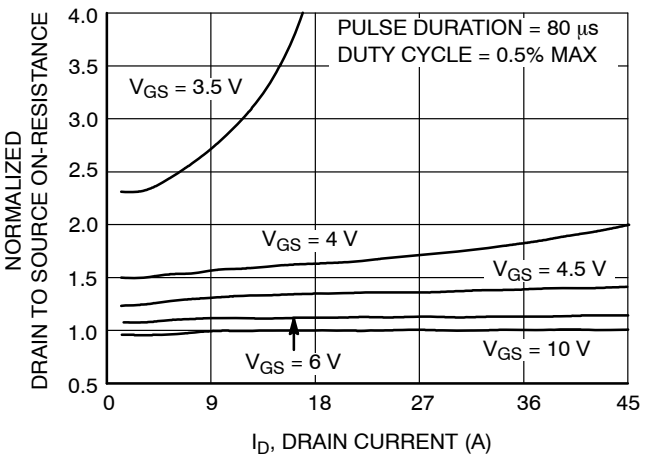

Figure 2. Normalized On-Resistance vs. Drain Current and Gate Voltage

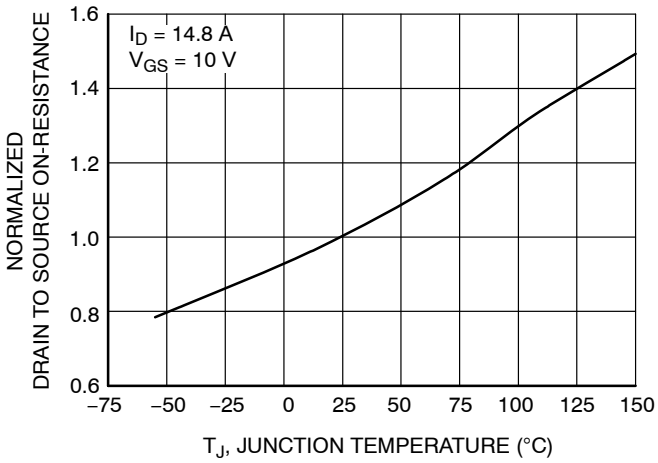

Figure 3. Normalized On-Resistance vs. Junction Temperature

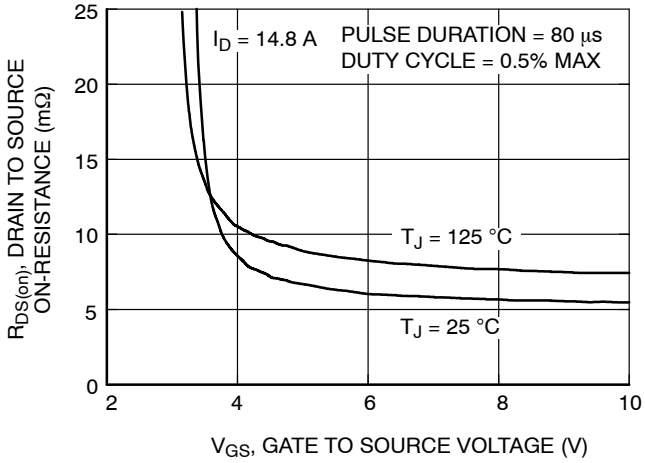

Figure 4. On-Resistance vs. Gate to Source Voltage

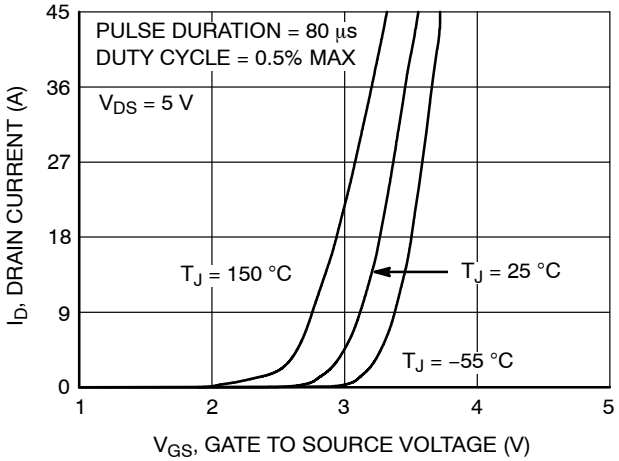

Figure 5. Transfer Characteristics

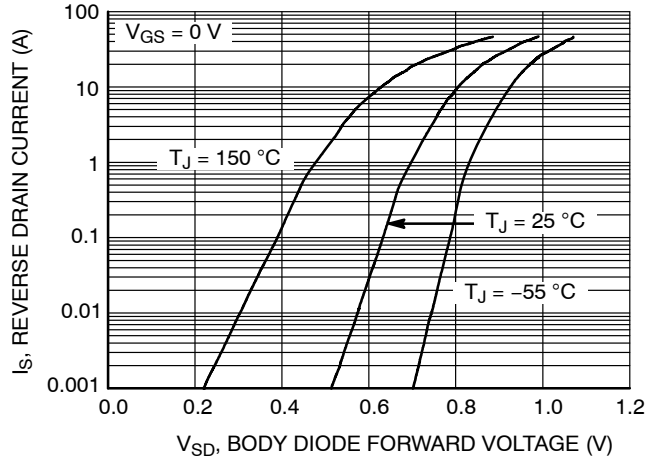

Figure 6. Source to Drain Diode Forward Voltage vs. Source Current

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TYPICAL CHARACTERISTICS (continued)

(T_J = 25 °C unless otherwise noted)

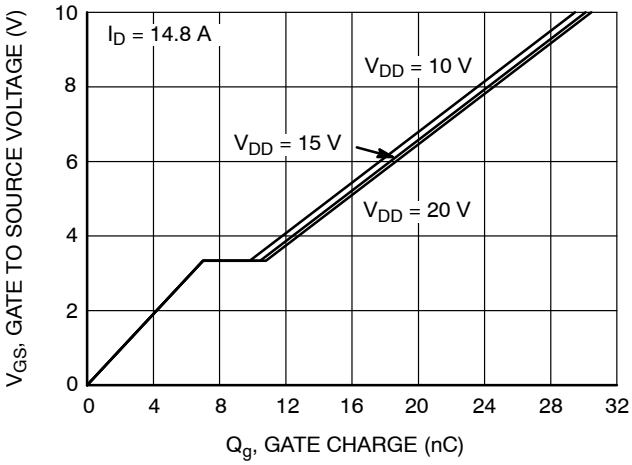

Figure 7. Gate Charge Characteristics

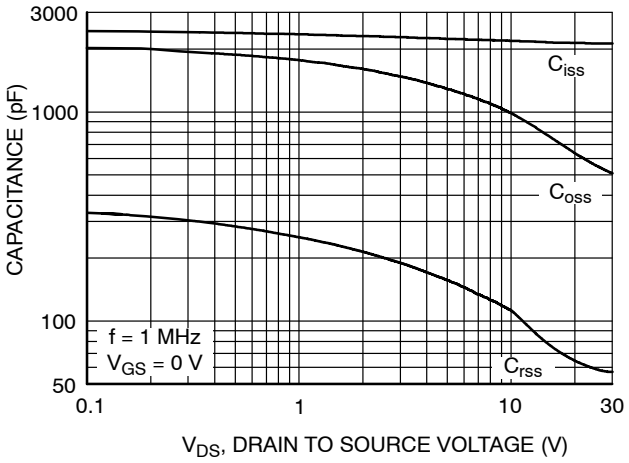

Figure 8. Capacitance vs. Drain to Source Voltage

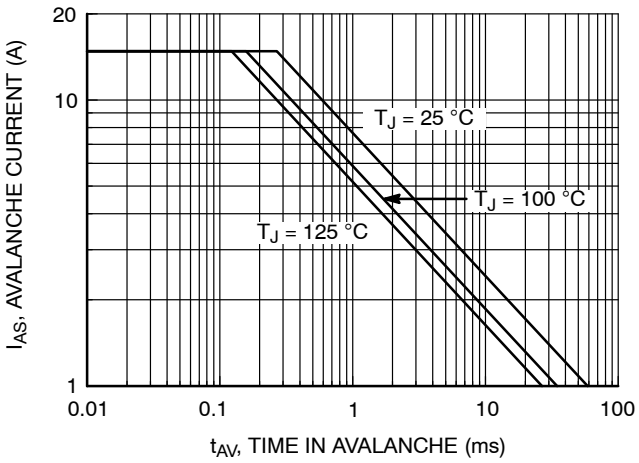

Figure 9. Unclamped Inductive Switching Capability

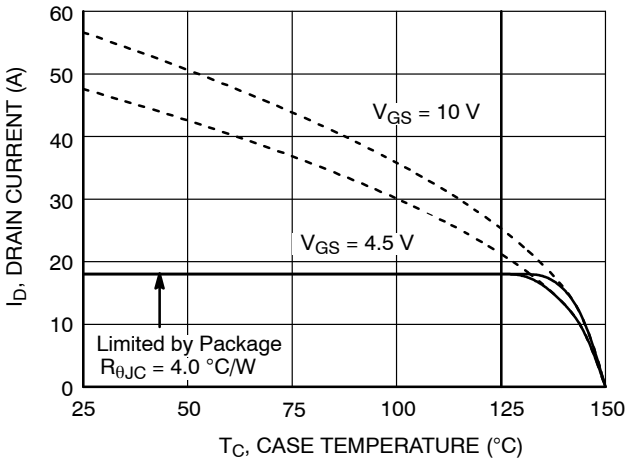

Figure 10. Maximum Continuous Drain Current vs. Case Temperature

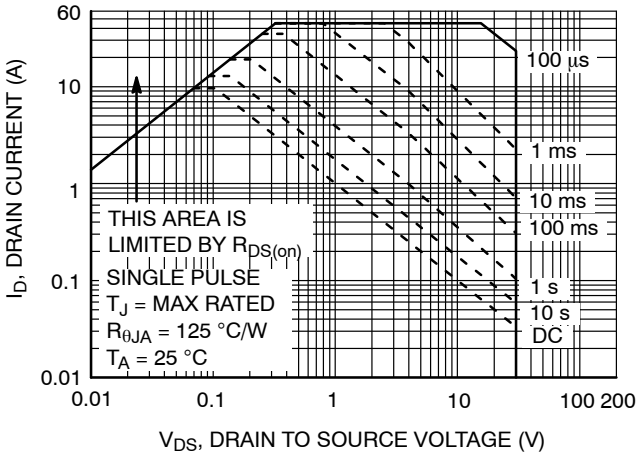

Figure 11. Forward Bias Safe Operating Area

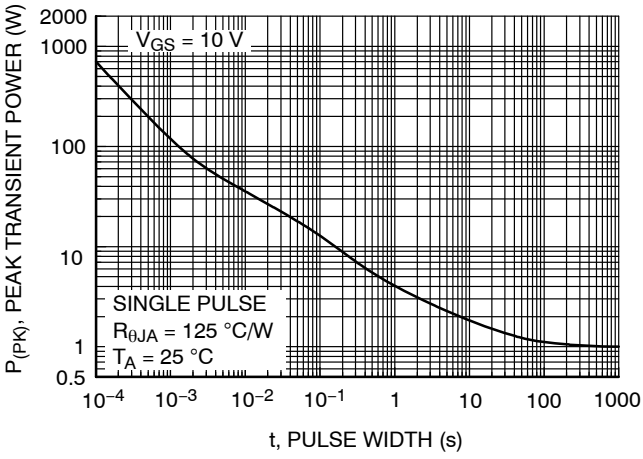

Figure 12. Single Pulse Maximum Power Dissipation

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TYPICAL CHARACTERISTICS (continued)

(T_J = 25 °C unless otherwise noted)

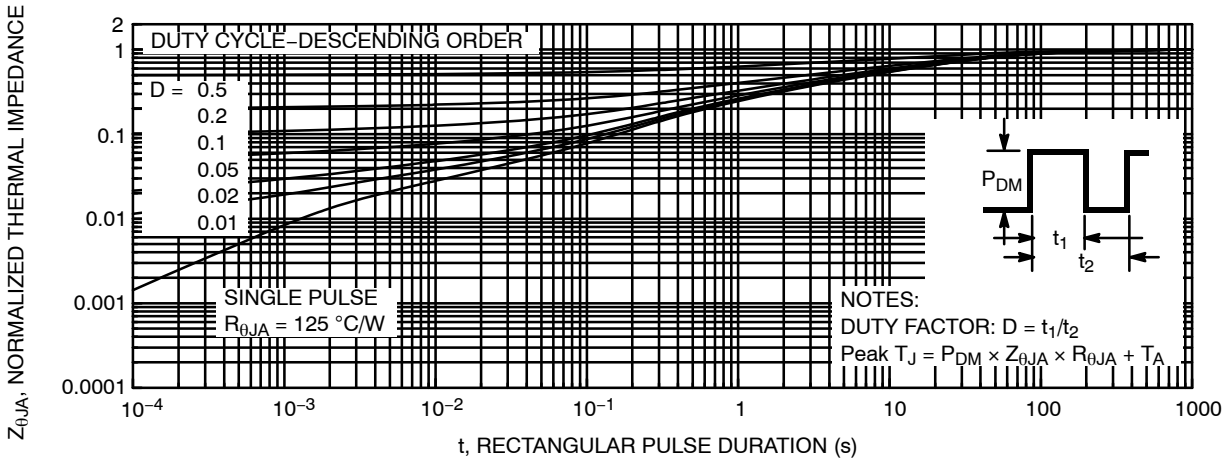

Figure 13. Transient Thermal Response Curve

ORDERING INFORMATION

Device	Package	Shipping†
FDMC7680	WDFN8 (Pb-Free, Halide Free)	3000/ Tape & Reel

† For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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REVISION HISTORY

Revision	Description of Changes	Date
4	Change **onsemi** template + Updating Marking diagram	11/4/2026

This document has undergone updates prior to the inclusion of this revision history table. The changes tracked here only reflect updates made on the noted approval dates.

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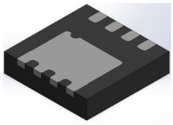
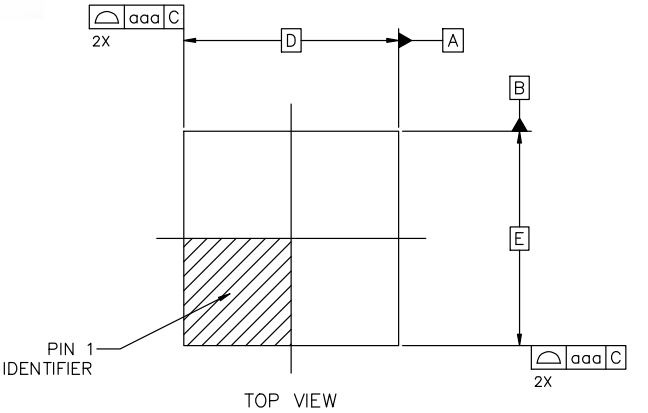


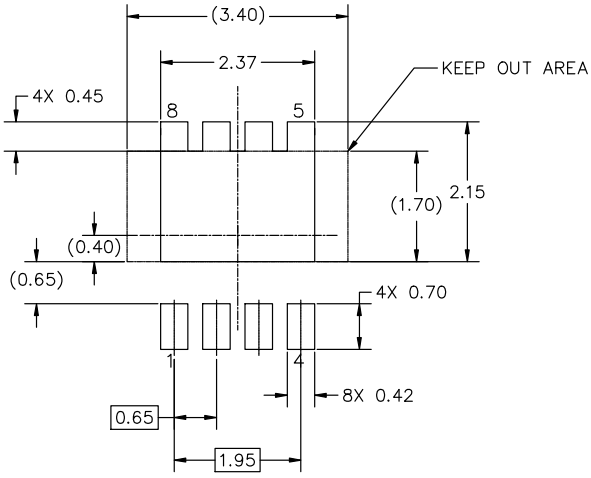
WDFN−8 3.30x3.30x0.75, 0.65P
CASE 511DH
ISSUE A

DATE 04 DEC 2025



NOTES:
1. DIMENSIONING AND TOLERANCING AS PER ASME Y14.5M, 2018.
2. CONTROLLING DIMENSION: MILLIMETERS.

MILLIMETERS			
DIM	MIN	NOM	MAX
A	0.70	0.75	0.80
A1	0.00	0.025	0.05
A3		0.20 REF	
b	0.30	0.35	0.40
D		3.30 BSC	
D2	2.22	2.27	2.32
E		3.30 BSC	
E2	1.95	2.00	2.05
e		0.65 BSC	
k		0.80 REF	
k1		0.50 REF	
L	0.45	0.50	0.55
L1	0.25	0.30	0.35
TOLERANCE FORM & POSITION			
aaa		0.05	
bbb		0.10	
ccc		0.10	
ddd		0.05	
eee		0.08	



RECOMMENDED MOUNTING FOOTPRINT

* For additional information on our Pb−Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques reference manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



XXXX = Specific Device Code
A = Assembly Location
Y = Year
WW = Work Week

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

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DESCRIPTION:	**WDFN−8 3.30x3.30x0.75, 0.65P**	**PAGE 1 OF 1**

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For additional information, please contact your local Sales Representative at www.onsemi.com/support/sales

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Parça koduyla arama

Üretici parça numarasını yazın; stok ve fiyatı hemen görün.

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Ürün kategorileri

Entegreden kapasitöre tüm elektronik komponent kategorileri.

Kategorilere göz atın

Üreticiler

Aradığınız üreticinin ürünlerini tek sayfada inceleyin.

Üreticileri görün

Toplu alım ve teklif

Listede olmayan ya da yüksek adetli parçalar için teklif isteyin.

Teklif isteyin

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